

Data sheet acquired from Harris Semiconductor

CD74HC86, CD74HCT86

High Speed CMOS Logic Quad 2-Input EXCLUSIVE OR Gate

August 1997

Features

- Typical Propagation Delay: 9ns at V_{CC} = 5V, $C_L = 15pF, T_A = 25^{\circ}C$
- Fanout (Over Temperature Range)
 - Standard Outputs...... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: NIL = 30%, NIH = 30% of VCC at $V_{CC} = 5V$
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, $V_{IL} = 0.8V \text{ (Max)}, V_{IH} = 2V \text{ (Min)}$
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Applications

- Logical Comparators
- Parity Generators and Checkers
- · Adders and Subtractors

Description

The Harris CD74HC86, CD74HCT86 contain independent EXCLUSIVE OR gates in one package. They provide the system designer with a means for implementation of the EXCLUSIVE OR function. Logic gates utilize silicon gate CMOS technology to achieve operating speeds similar to LSTTL gates with the low power consumption of standard CMOS integrated circuits. All devices have the ability to drive 10 LSTTL loads. The 74HCT logic family is functionally pin compatible with the standard 74LS logic family.

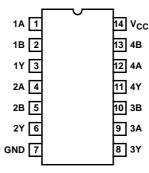
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74HC86E	-55 to 125	14 Ld PDIP	E14.3
CD74HCT86E	-55 to 125	14 Ld PDIP	E14.3
CD74HC86M	-55 to 125	14 Ld SOIC	M14.15
CD74HCT86M	-55 to 125	14 Ld SOIC	M14.15
CD54HC86W	-55 to 125	Wafer	
CD54HCT86W	-55 to 125	Wafer	
CD54HC86H	-55 to 125	Die	

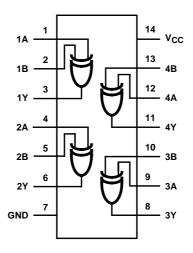
NOTE: When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

Pinout

CD74HC86, CD74HCT86 (PDIP, SOIC) TOP VIEW



Functional Diagram

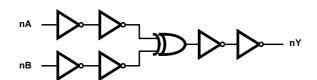


TRUTH TABLE

INP	OUT PU T	
nA	nB 🚜	nY
L	3 37	1
L	Har CO	Н
Н	L .	Н
Н	Н	L

NOTE: H = High Voltage Level, L = Low Voltage Level

Logic Symbol



Absolute Maximum Ratings Thermal Information θ_{JA} (°C/W) DC Supply Voltage, VCC $\,$ -0.5V to 7V $\,$ Thermal Resistance (Typical, Note 1) DC Input Diode Current, I_{IK} 100 SOIC Package..... DC Output Diode Current, IOK For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$±20mA Maximum Storage Temperature Range-65°C to 150°C DC Output Source or Sink Current per Output Pin, IO Maximum Lead Temperature (Soldering 10s).....300°C For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$±25mA (SOIC - Lead Tips Only) **Operating Conditions** Temperature Range (T_{Δ})55°C to 125°C Supply Voltage Range, V_{CC} HC Types2V to 6V DC Input or Output Voltage, V_I, V_O 0V to V_{CC} Input Rise and Fall Time

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

1. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

DC Electrical Specifications

			ST TIONS		2 5 °C		-40°C T	O +85°C	-55°C TO 125°C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	МАХ	MIN	MAX	MIN	MAX	UNITS
HC TYPES							-				-	
High Level Input	VIH	1		2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	ı	-	3.15	-	3.15	-	V
				6	4.2	ı	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	ı	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	ı	1.35	-	1.35		1.35	V
				6	-	-	1.8	-	1.8	-	1.8	٧
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	i	-	1.9	-	1.9	-	V
Voltage CMOS Loads		V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	٧
			-0.02	6	5.9	-	-	5.9	-	5.9	-	٧
High Level Output			-4	4.5	3.98	ı	-	3.84	-	3.7	-	V
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	٧
Voltage CMOS Loads		V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			4	4.5	-	-	0.26	-	0.33	-	0.4	٧
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	٧
Input Leakage Current	I _I	V _{CC} or GND	-	6	-	-	±0.1	-	±1	i	±1	μА
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	-	2	-	20	-	40	μА

DC Electrical Specifications (Continued)

			ST ITIONS		25°C		-40°C T	O +85°C	-55°C TO 125°C			
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	٧
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{ОН}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	-0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	五十	0.33	-	0.4	V
Input Leakage Current	Ι _Ι	V _{CC} and GND	0	5.5	182	3	±0.1	1.0	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	1	10	2	-	20	-	40	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load (Note 2)	Δl _{CC}	V _{CC} -2.1		4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
All	1

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. $360\mu A$ max at $25^{\circ}C$.

Switching Specifications Input t_{r} , $t_{f} = 6 \text{ns}$

		TEST	v _{cc}	25°C		-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	(8)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES							_	_	_		
Propagation Delay,Input to Output (Figure 1)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	120	-	150	-	180	ns
			4.5	-	-	24	-	30	-	36	ns
			6	-	-	20	-	26	-	31	ns
Propagation Delay, Data Input to Output Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	9	-	-	-	-	-	ns
Transition Times (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns

^{2.} For dual-supply systems theorectical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST	v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	22	-	-	-	-	-	pF
HCT TYPES	HCT TYPES										
Propagation Delay, Input to Output (Figure 2)	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	32	-	40	-	48	ns
Propagation Delay, Data Input to Output Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	13	-	-	-	-	-	ns
Transition Times (Figure 2)	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	27	-	-	-	-	-	pF

NOTES:

- 3. C_{PD} is used to determine the dynamic power consumption, per gate.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms

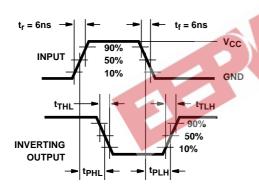


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

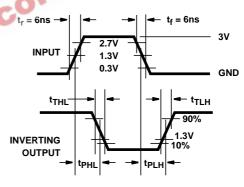


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

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